### **SKIIP 22NAB126V10**



MiniSKiiP<sup>®</sup> 2

**SKiiP 22NAB126V10** 

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter

#### **Features**

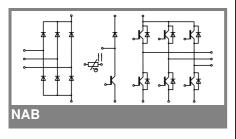
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

#### Typical Applications\*

- Inverter up to 10 kVA
- Typical motor power 5,5 kW

#### Remarks

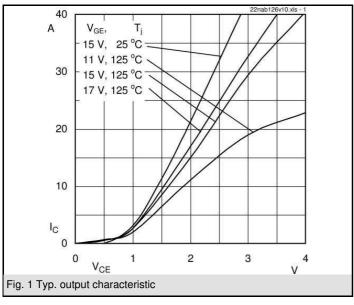
• V<sub>CEsat</sub> , V<sub>F</sub> = chip level value

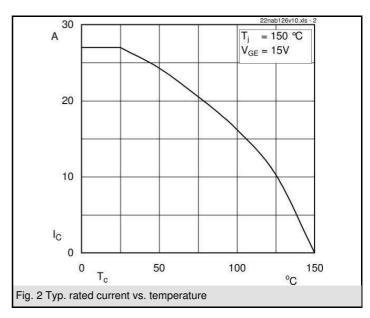


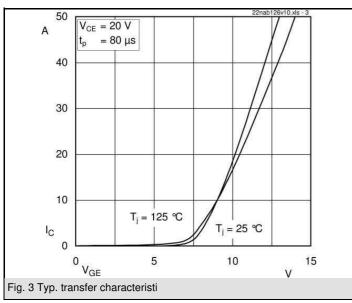
<b>Absolute Maximum Ratings</b> T <sub>s</sub> = 25 °C, unless otherwise specified							
Symbol	Conditions	Values	Units				
IGBT - Inverter, Chopper							
$V_{CES}$		1200	V				
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	28 (22)	Α				
I <sub>CRM</sub>		30	Α				
$V_{GES}$		± 20	V				
T <sub>j</sub>		- 40 <b>+</b> 150	°C				
Diode - Inverter, Chopper							
I <sub>F</sub>	$T_s = 25 (70) ^{\circ}C$	26 (20)	Α				
I <sub>FRM</sub>		30	Α				
T <sub>j</sub>		- 40 <b>+</b> 150	°C				
Diode - Rectifier							
$V_{RRM}$		1600	V				
I <sub>F</sub>	T <sub>s</sub> = 70 °C	61	Α				
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180 °, T <sub>i</sub> = 25 °C	700	Α				
i²t	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$	2400	A²s				
T <sub>j</sub>		- 40 <b>+</b> 150	°C				
Module							
I <sub>tRMS</sub>	per power terminal (20 A / spring)	40	Α				
T <sub>stg</sub>		- 40 <b>+</b> 125	°C				
V <sub>isol</sub>	AC, 1 min.	2500	V				

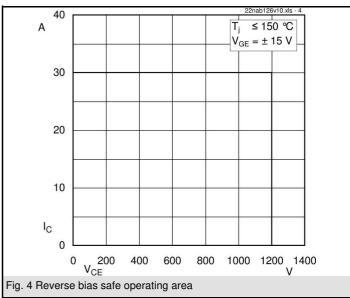
Characte	ristics	s = 25 °C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter, Chopper								
$V_{CEsat}$	I <sub>Cnom</sub> = 15 A, T <sub>i</sub> = 25 (125) °C		1,7 (2)	2,1 (2,4)	V			
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}$ , $I_C = 0.6$ mA	5	5,8	6,5	V			
V <sub>CE(TO)</sub>	T <sub>j</sub> = 25 (125) °C		1 (0,9)	1,2 (1,1)	V			
r <sub>T</sub>	$T_j = 25 (125) ^{\circ}C$		47 (73)	60 (87)	mΩ			
C <sub>ies</sub>	$V_{CE}^{J}$ = 25 V, $V_{GE}$ = 0 V, f = 1 MHz		1		nF			
C <sub>oes</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,1		nF			
C <sub>res</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,1		nF			
R <sub>th(j-s)</sub>	per IGBT		1,15		K/W			
t <sub>d(on)</sub>	under following conditions		25		ns			
t <sub>r</sub>	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25		ns			
$t_{d(off)}$	$I_{Cnom} = 15 \text{ A}, T_j = 125^{\circ}\text{C}$		385		ns			
$t_{f}$	$R_{Gon} = R_{Goff} = 30 \Omega$		90		ns			
Ė <sub>on</sub>	inductive load		2		mJ			
E <sub>off</sub>			1,9		mJ			
Diode - Inverter, Chopper								
$V_F = V_{EC}$	I <sub>Fnom</sub> = 15 A, T <sub>i</sub> = 25 (125) °C	1	1,6 (1,6)	1,8 (1,8)	V			
V <sub>(TO)</sub>	$T_i = 25 (125) °C$		1 (0,8)	1,1 (0,9)	V			
r <sub>T</sub>	T <sub>i</sub> = 25 (125) °C		40 (53)	47 (60)	mΩ			
$R_{th(j-s)}$	per diode		1,95		K/W			
I <sub>RRM</sub>	under following conditions		25		Α			
$Q_{rr}$	I <sub>Fnom</sub> = 15 A, V <sub>R</sub> = 600 V		3		μC			
E <sub>rr</sub>	$V_{GE} = 0 \text{ V}, T_j = 125 \text{ °C}$		1,1		mJ			
	$di_F/dt = 900 \text{ A/}\mu\text{s}$							
Diode - Rectifier								
$V_{F}$	I <sub>Fnom</sub> = 35 A, T <sub>i</sub> = 25 °C	1	1,1		V			
V <sub>(TO)</sub>	T <sub>i</sub> = 150 °C		0,8		V			
r <sub>T</sub>	T <sub>i</sub> = 150 °C		11		mΩ			
R <sub>th(j-s)</sub>	per diode		0,9		K/W			
Temperature Sensor								
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C		1000(1670)		Ω			
Mechanical Data								
w			95		g			
$M_s$	Mounting torque	2		2,5	Nm			

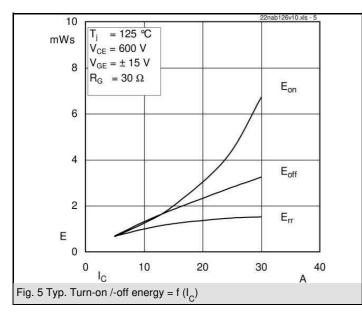
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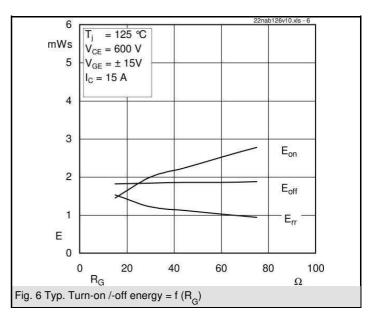




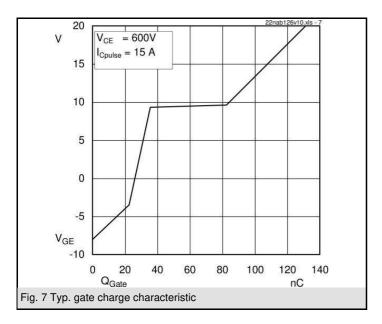


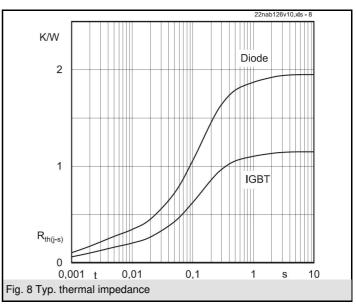


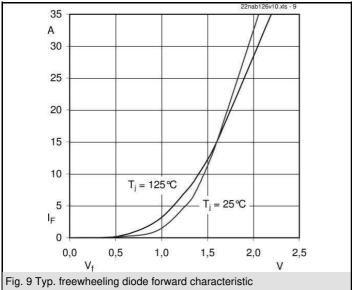


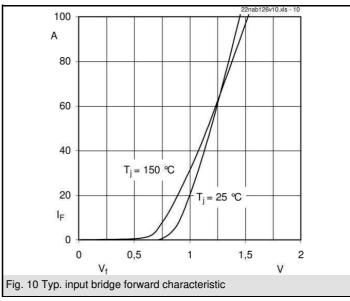


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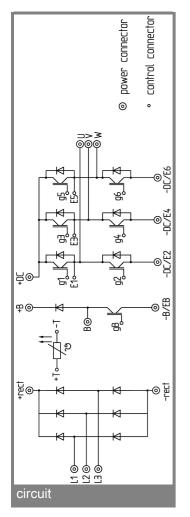


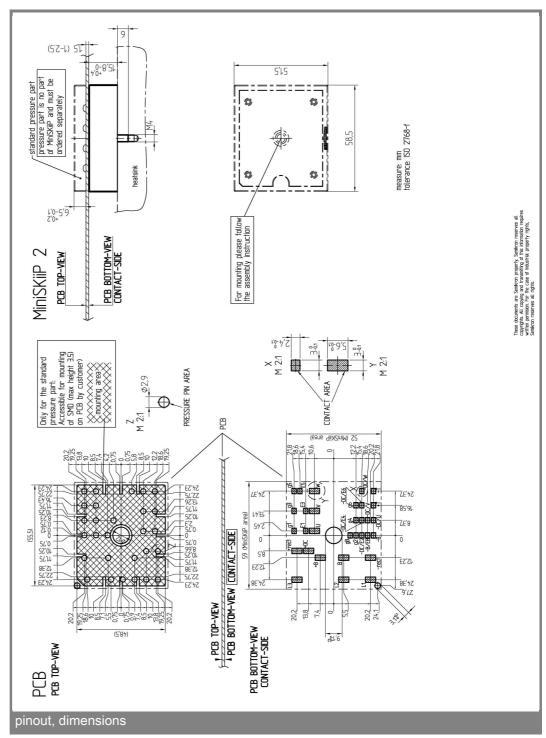






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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

#### \*IMPORTANT INFORMATION AND WARNINGS

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